

Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs.
- Low power loss and soft switching.
- High performance and high reliability IGBT with overheating protection.
- Both P-side and N-side alarm output available.
- Higher reliability because of a big decrease in number of parts in built-in control circuit.

Maximum ratings and characteristics

- Absolute maximum ratings(at Tc=25°C unless otherwise specified)

Item			Symbol	Rating		Unit
				Min.	Max.	
Bus voltage	DC		V _{DC}	0	900	V
	Surge		V _{DC(surge)}	0	1000	V
	Short operating		V _{SC}	200	800	V
Collector-Emitter voltage *1			V _{CES}	0	1200	V
Inverter	Collector current	DC	I _C	-	50	A
		1ms	I _{CP}	-	100	A
		Duty=98.0% *2	-I _C	-	50	A
Brake	Collector power dissipation	One transistor *3	P _C	-	357	W
	Collector current	DC	I _C	-	25	A
		1ms	I _{CP}	-	50	A
	Forward Current of Diode		I _F	-	25	A
	Collector power dissipation	One transistor *3	P _C		198	W
Supply voltage of Pre-Driver *4			V _{CC}	-0.5	20	V
Input signal voltage *5			V _{in}	-0.5	V _{CC} +0.5	V
Input signal current			I _{in}	-	3	mA
Alarm signal voltage *6			V _{ALM}	-0.5	V _{CC}	V
Alarm signal current *7			I _{ALM}	-	20	mA
Junction temperature			T _j	-	150	°C
Operating case temperature			T _{opr}	-20	100	°C
Storage temperature			T _{stg}	-40	125	°C
Isolating voltage (Terminal to base, 50/60Hz sine wave 1min.)			V _{iso}	-	AC2500	V
Screw torque	Terminal (M5)			-	3.5	N·m
	Mounting (M5)			-	3.5	N·m

Note

*1 : V_{CES} shall be applied to the input voltage between terminal P and U or V or W or DB, N and U or V or W or DB.

*2 : 125°C/FRD R_{th(j-c)}/(I_C × V_F Max.)=125/0.85(50×3.0)×100=98.0%

*3 : P_C=125°C/IGBT R_{th(j-c)}=125/0.35=357W [Inverter]

P_C=125°C/IGBT R_{th(j-c)}=125/0.63=198W [Inverter]

*4 : V_{CC} shall be applied to the input voltage between terminal No.4 and 1, 8 and 5, 12 and 9, 14 and 13

*5 : V_{in} shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9, 15,16,17,18 and 13.

*6 : V_{ALM} shall be applied to the voltage between terminal No.2 and 1, No6 and 5, No10 and 9, No.19 and 13.

*7 : I_{ALM} shall be applied to the input current to terminal No.2,6,10 and 19.

Electrical characteristics (at Tc=Tj=25°C, Vcc=15V unless otherwise specified.)

● Main circuit

Item		Symbol	Condition		Min.	Typ.	Max.	Unit
Inverter	Collector current at off signal input	ICES	VCE=1200V Vin terminal open.		-	-	1.0	mA
	Collector-Emitter saturation voltage	VCE(sat)	Ic=50A	Terminal	-	-	2.6	V
				Chip	-	-	-	
	Forward voltage of FWD	VF	-Ic=50A	Terminal	-	-	3.0	V
				Chip	-	-	-	
Brake	Collector current at off signal input	ICES	VCE=1200V Vin terminal open.		-	-	1.0	mA
	Collector-Emitter saturation voltage	VCE(sat)	Ic=25A	Terminal	-	-	2.6	V
	Forward voltage of Diode	VF	-Ic=25A	Terminal	-	-	3.3	
Turn-on time		ton	VDC=600V,Tj=125°C		1.2	-	-	μs
Turn-off time		toff	IC=50A Fig.1, Fig.6		-	-	3.6	
Reverse recovery time		trr	VDC=600V, IF=50A Fig.1, Fig.6		-	-	0.3	

● Control circuit

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Supply current of P-line side pre-driver(one unit)	Iccp	Switching Trequency : 0 to 15kHz Tc=-20 to 125°C Fig.7	-	-	18	mA
Supply current of N-line side pre-driver	ICCN		-	-	65	mA
Input signal threshold voltage (on/off)	Vin(th)	ON	1.00	1.35	1.70	V
		OFF	1.25	1.60	1.95	V
Input zener voltage	VZ	Rin=20k ohm	-	8.0	-	V
Alarm signal hold time	tALM	Tc=-20°C Fig.2	1.1	-	-	ms
		Tc=25°C Fig.2	-	2.0	-	ms
		Tc=125°C Fig.2	-	-	4.0	ms
Limiting Resistor for Alarm	RALM		1425	1500	1575	ohm

● Protection Section (Vcc=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Over Current Protection Level of Inverter circuit	Ioc	Tj=125°C	75	-	-	A
Over Current Protection Level of Brake circuit	Ioc	Tj=125°C	38	-	-	A
Over Current Protection Delay time	tdoc	Tj=125°C	-	10	-	μs
SC Protection Delay time	tsc	Tj=125°C Fig.4	-	-	12	μs
IGBT Chip Over Heating Protection Temperature Level	TjOH	Surface of IGBT chips	150		-	°C
Over Heating Protection Hysteresis	TjH		-	20	-	°C
Over Heating Protection Protection Temperature Level	TcOH	Vdc=0V, Ic=0A Case Temperature	110	-	125	°C
Over Heating Protection Hysteresis	TcH		-	20	-	°C
Under Voltage Protection Level	VUV		11.0	-	12.5	V
Under Voltage Protection Hysteresis	VH		0.2	0.5	-	V

● Thermal characteristics(Tc=25°C)

Item		Symbol	Min.	Typ.	Max.	Unit
Junction to Case thermal resistance *8	Inverter	IGBT	Rth(j-c)	-	0.35	°C/W
		FWD	Rth(j-c)	-	0.85	°C/W
	Brake	IGBT	Rth(j-c)	-	0.63	°C/W
Case to fin thermal resistance with compound			Rth(c-f)	-	0.05	-

*8 : (For 1 device, Case is under the device)

● Noise Immunity (VDC=300V, Vcc=15V, Test Circuit Fig.5)

Item	Condition	Min.	Typ.	Max.	Unit
Common mode rectangular noise	Pulse width 1μs, polarity ±, 10minuets Judge : no over-current, no miss operating	±2.0	-	-	kV
Common mode lightning surge	Rise time 1.2μs, Fall time 50μs Interval 20s, 10 times Judge : no over-current, no miss operating	±5.0	-	-	kV

● Recommendable value

Item	Symbol	Min.	Typ.	Max.	Unit
DC Bus Voltage	VDC	-	-	800	V
Operating Supply Voltage of Pre-Driver	VCC	13.5	15.0	16.5	V
Screw torque (M5)	-	2.5	-	3.0	Nm

● Weight

Item	Symbol	Min.	Typ.	Max.	Unit
Weight	Wt	-	450	-	g

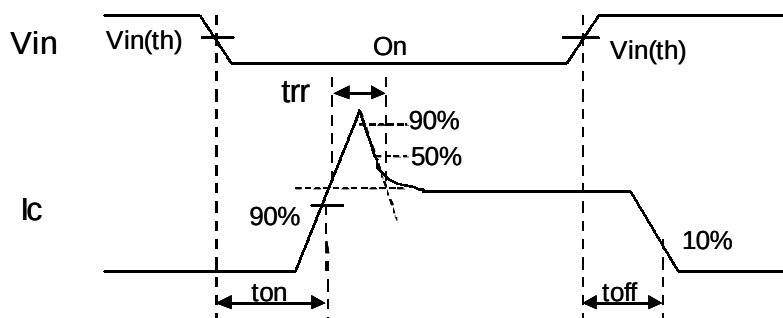
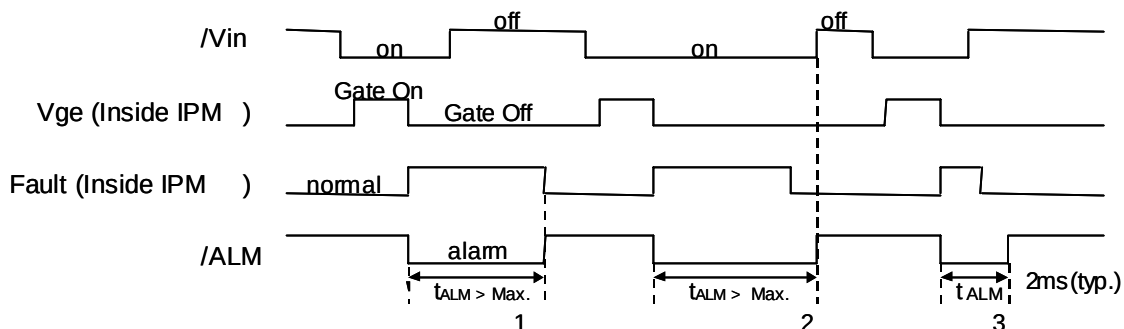


Figure 1. Switching Time Waveform Definitions



Fault : Over-current, Over-heat or Under-voltage

Figure 2. Input/Output Timing Diagram

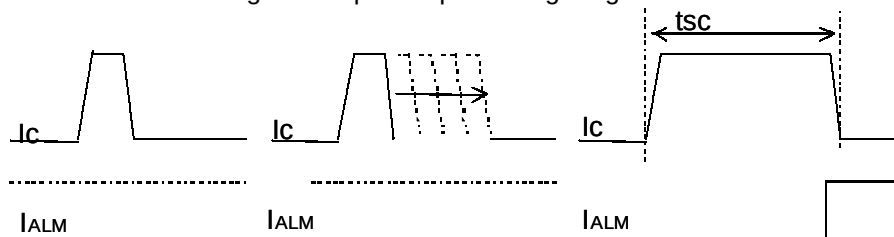


Figure.4 Definition of tsc

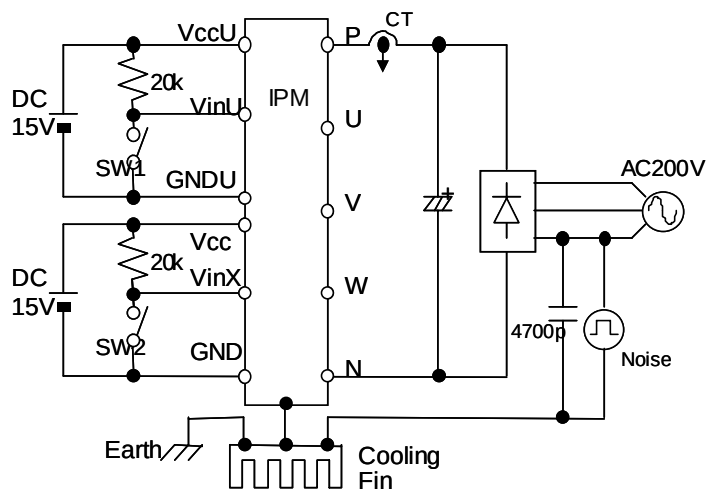


Figure 5. Noise Test Circuit

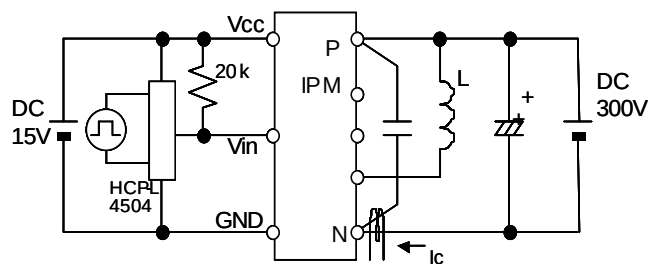


Figure 6. Switching Characteristics Test Circuit

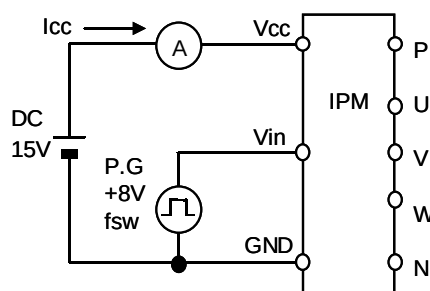


Figure 7. Icc Test Circuit

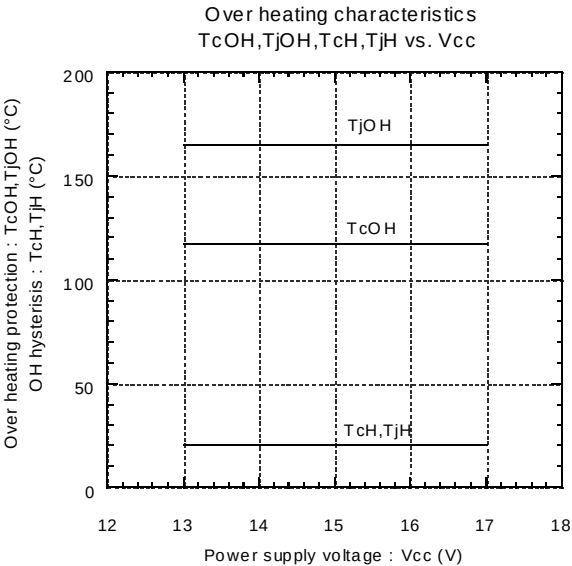
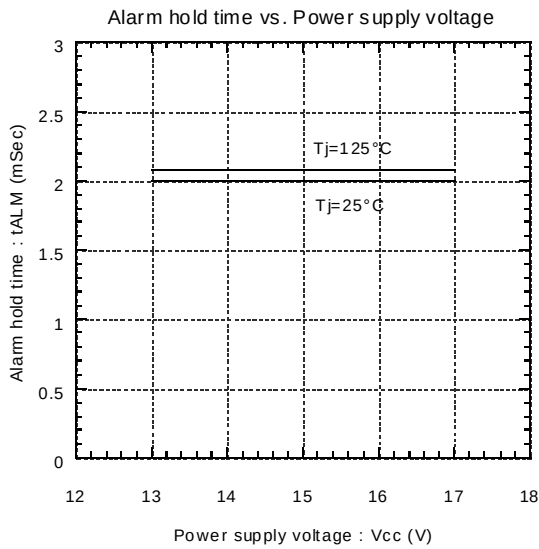
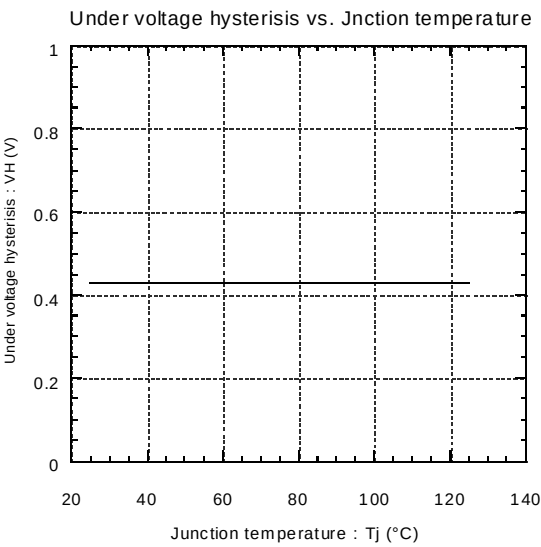
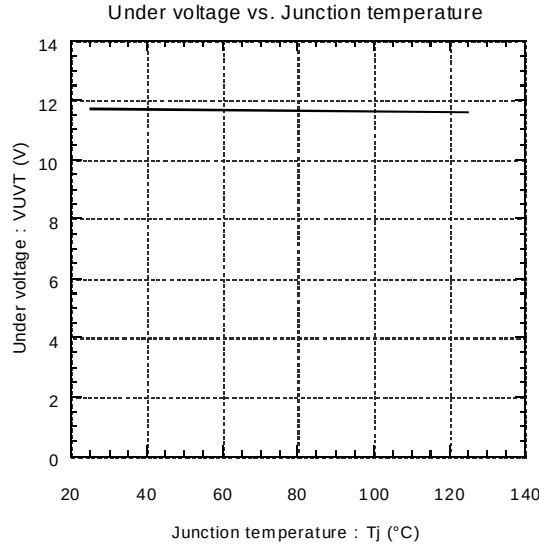
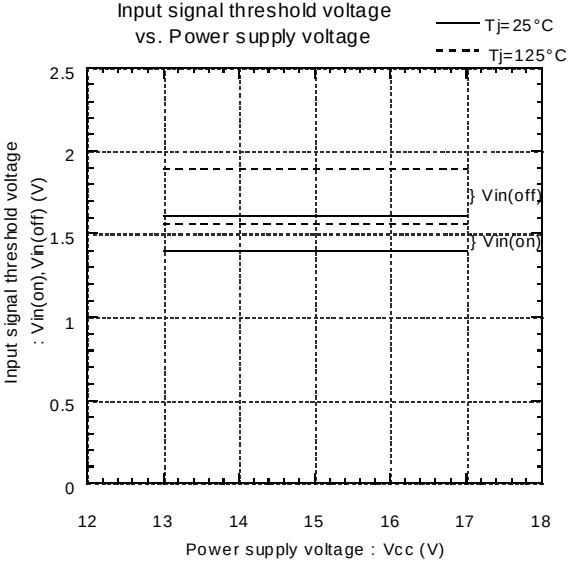
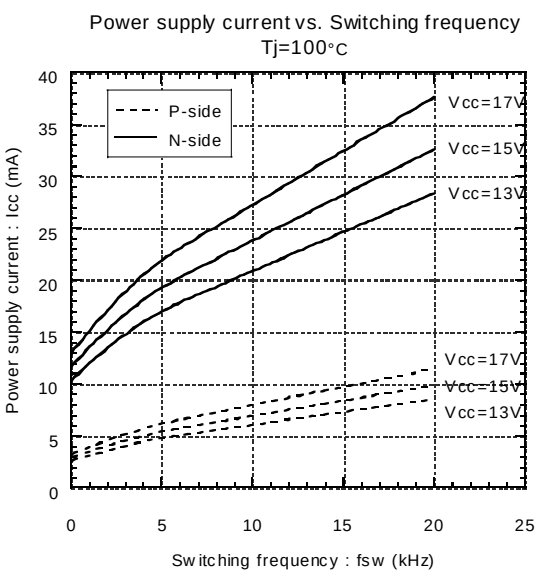
1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

[illegible]

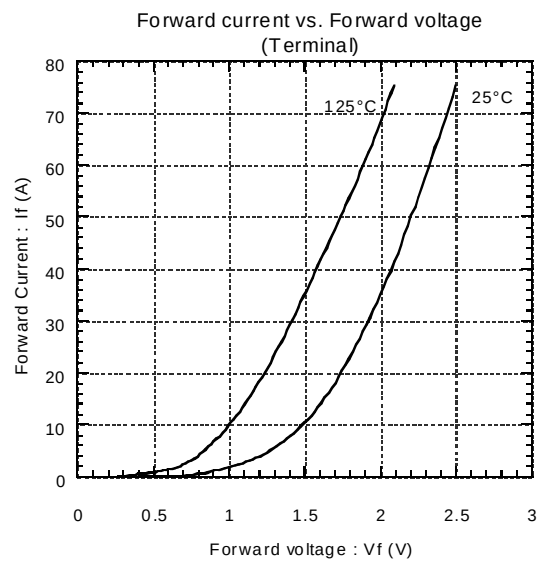
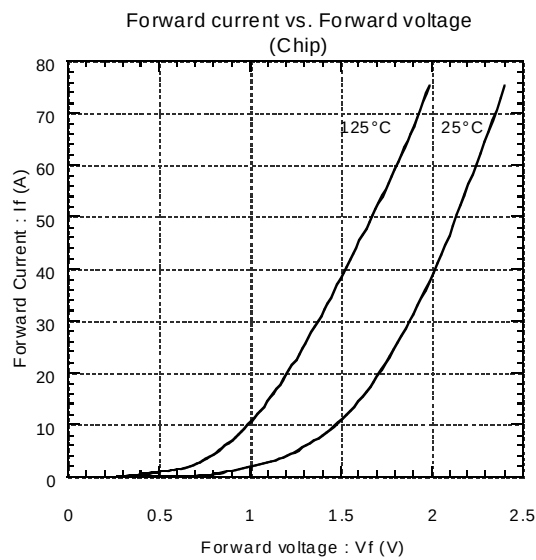
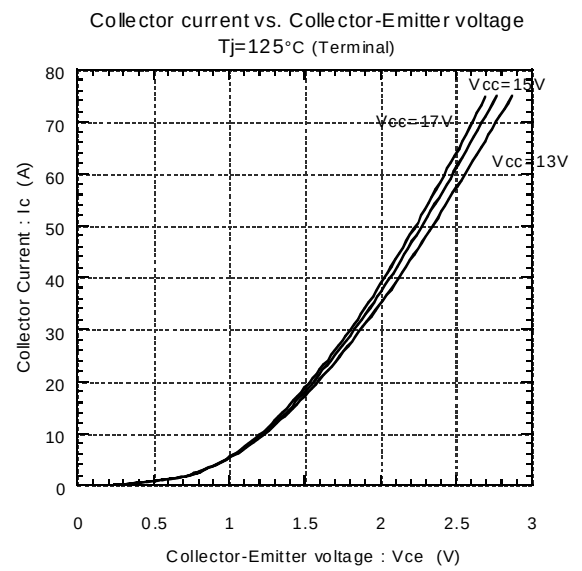
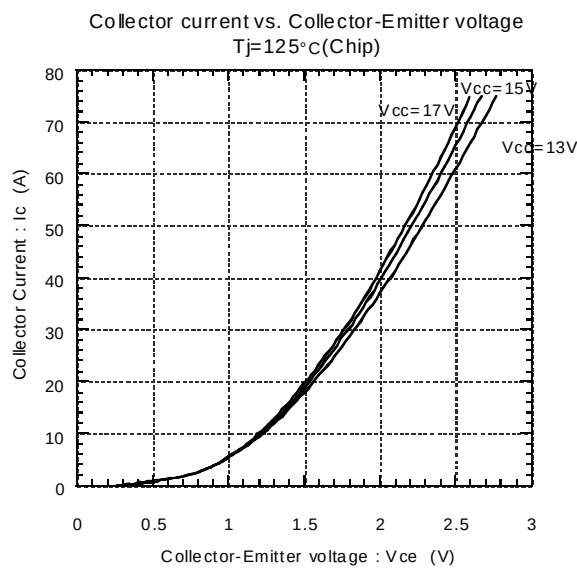
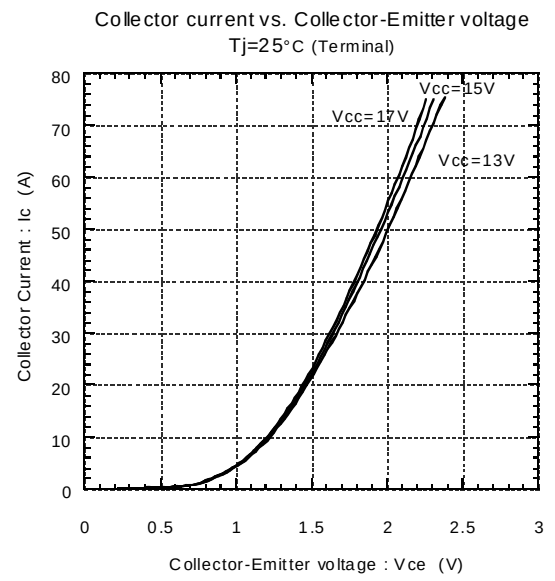
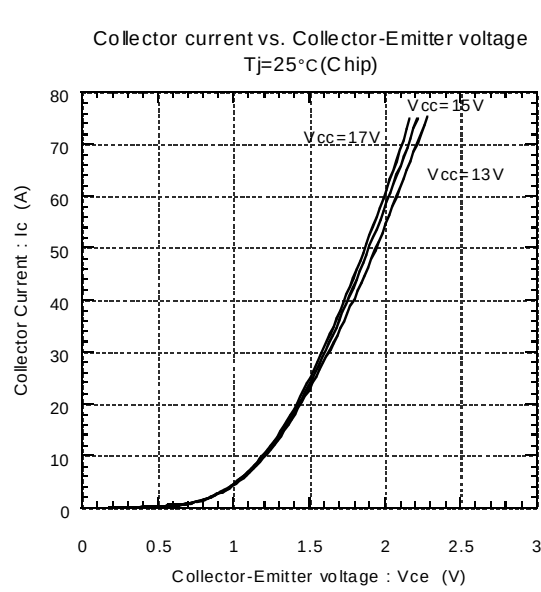
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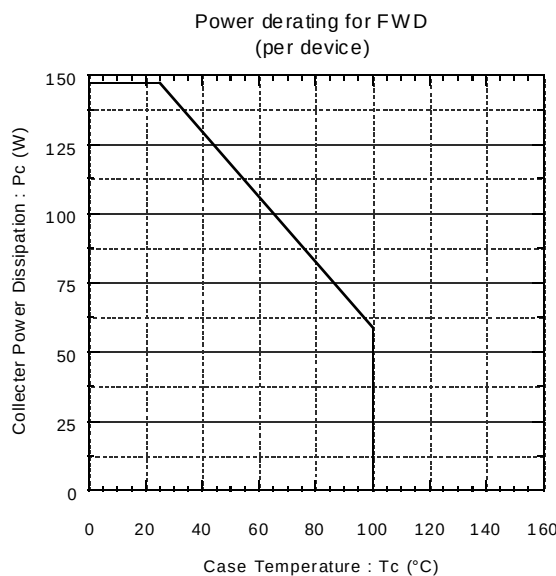
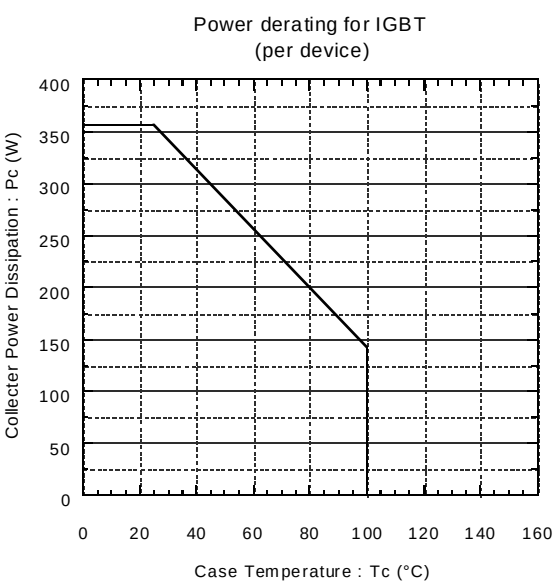
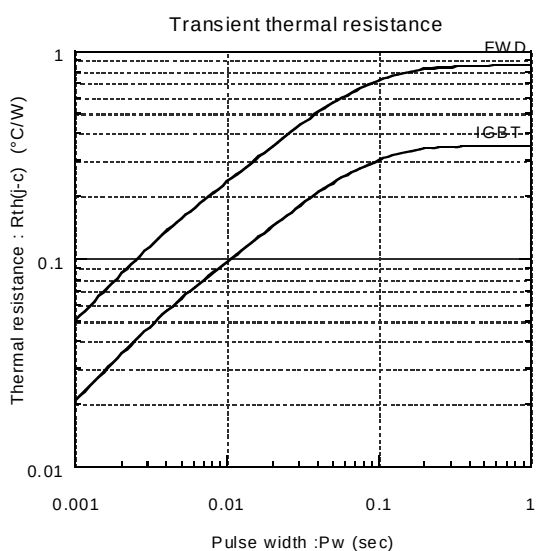
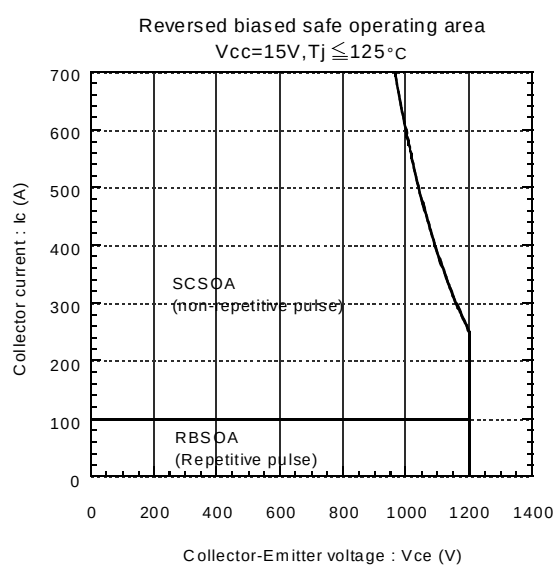
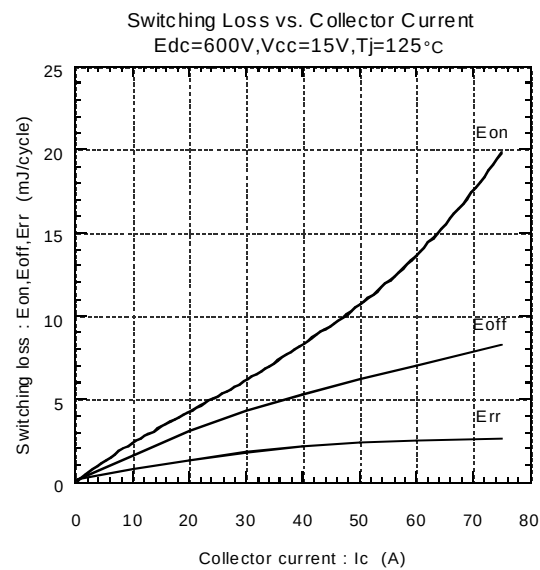
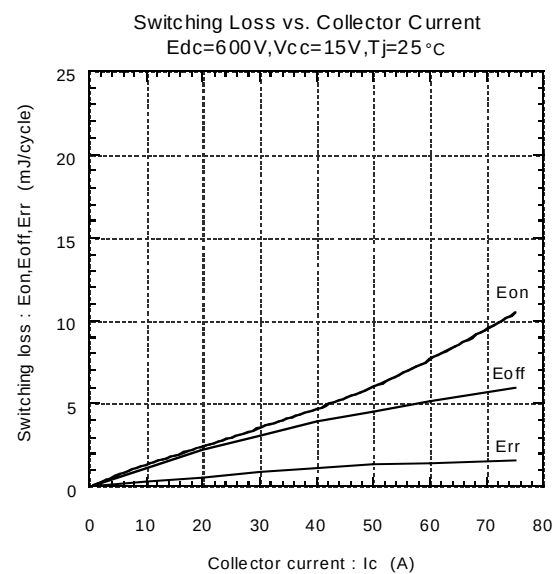
Characteristics

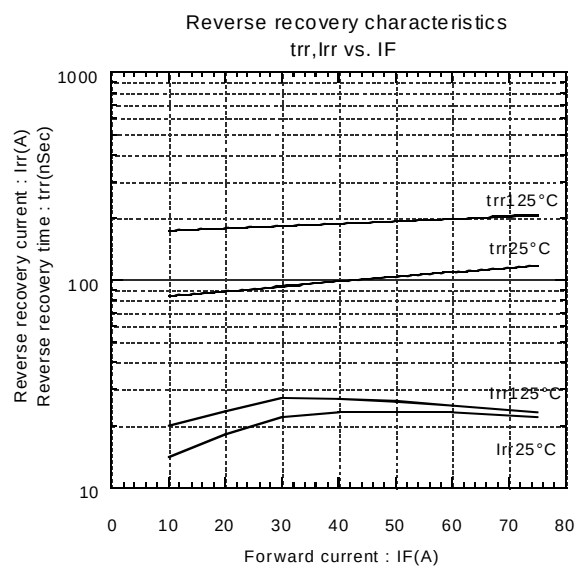
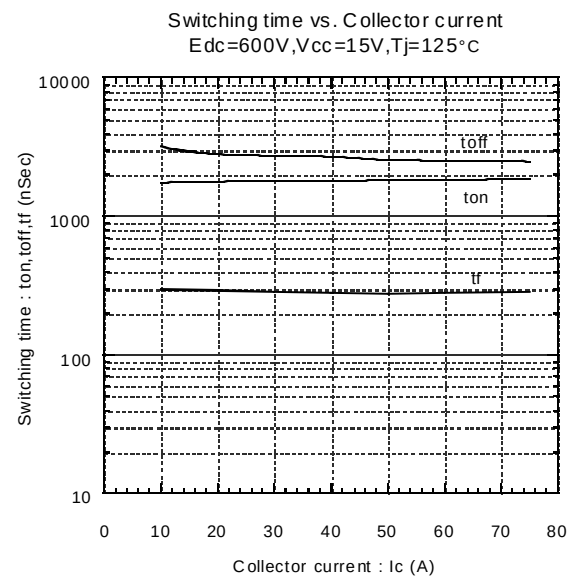
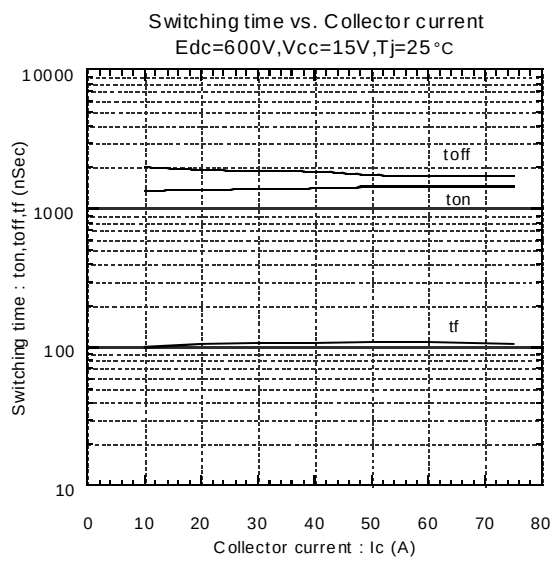
Control circuit characteristics (Representative)



● Main circuit characteristics (Representative)







● Dynamic Brake Characteristics (Representative)

